# NSN 5961-01-235-8889

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# Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

# Terminal Length:

0.500 inches

# **Overall Diameter:**

0.370 inches

# Internal Configuration:

Junction contact

# Mounting Method:

Terminal

# **Terminal Circle Diameter:**

0.200 inches

# Features Provided:

Hermetically sealed case and quality assurance level txv

# Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

175.0 collector to base voltage/static/emitter open and 175.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

1.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

300.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Inuclear hardness critical items, no drawing to determine if isc code 1 item should also be nuclear hardness. Can't change criticality code to reflect nuclear hardness; junction pattern arrangement: pnp

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

3 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/357 government specification

## Shelf Life:

N/a

# Unit Of Measure:

Domilitorization

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